

### **100V N-Channel MOSFET**

Voltage 100 V Current 5 A

#### **Features**

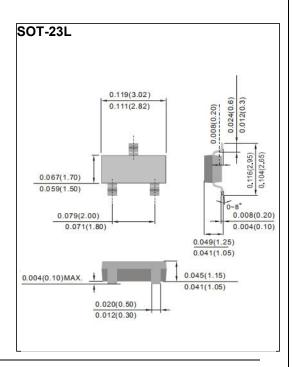
- $R_{DS(ON)}$ ,  $V_{GS}$ @10V, $I_D$ @4.5A<152m $\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}$ @4.5V, $I_{D}$ @3.0A<160 $m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance

#### **Mechanical Data**

• Case: SOT-23L Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25 C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	100	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	TC=25oC	ID	5	Α	
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	IDM	10		
Power Dissipation	TC=25°C	PD	31	W	
Continuous Drain Current	TA=25oC	ID	2.4	Α	
Power Dissipation	TA=25oC	PD	2.0	W	
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	1.8	mJ	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
	Junction to Ambient	R <sub>0JA</sub>	100		

• Limited only By Maximum Junction Temperature



# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =250uA	100	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250uA	1.0	1.72	2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =4.5A	-	130	152	mΩ
		V <sub>GS</sub> =4.5V,I <sub>D</sub> =3A	-	135	160	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =80V,V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	_	-	<u>+</u> 100	nA
Dynamic (Note 4)						
Total Gate Charge	$Q_g$	.,	-	19	-	nC
Gate-Source Charge	$Q_{gs}$	$V_{DS}$ =60V, $I_{D}$ =5A, $V_{GS}$ =10V (Note 2,3)	-	2.9	-	
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> -10V	-	3.2	-	
Input Capacitance	Ciss	), ozv.), ov.	-	1021	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V,	-	38	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	17	-	
Turn-On Delay Time	td <sub>(on)</sub>	V 50V.DI 500	-	6.1	-	
Turn-On Rise Time	t <sub>r</sub>	V <sub>DS</sub> =50V,RL=5.6Ω,	-	27	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =6 $\Omega$	-	28	-	
Turn-Off Fall Time	t <sub>f</sub>	, , ,	-	11	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	9	А
Diode Forward Current	Is					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	0.74	1.2	V

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH, I<sub>AS</sub>=6A, V<sub>DD</sub>=25V, V<sub>GS</sub>=10V
- 7. Guaranteed by design, not subject to production testing



### TYPICAL CHARACTERISTIC CURVES

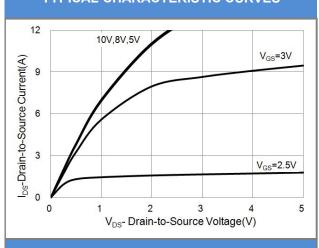
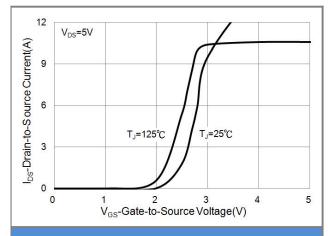


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

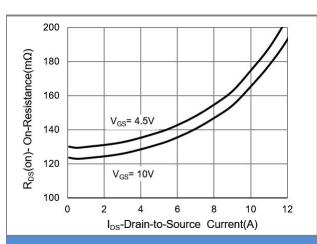


Fig.3 On-Resistance vs. Drain Current

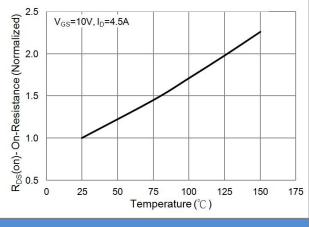


Fig.4 On-Resistance vs. Junction temperature

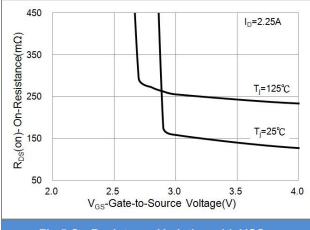
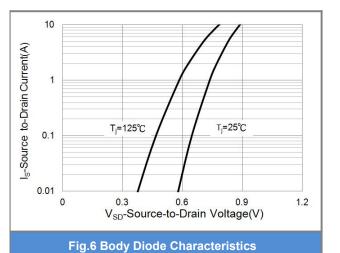


Fig.5 On-Resistance Variation with VGS.





#### **TYPICAL CHARACTERISTIC CURVES**

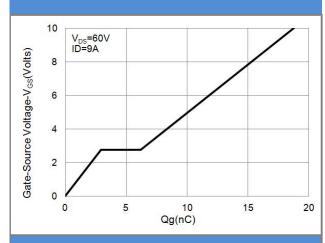


Fig.7 Gate-Charge Characteristics

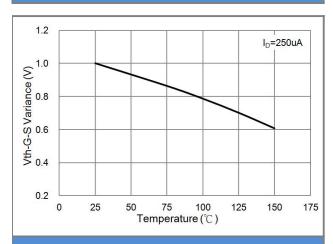
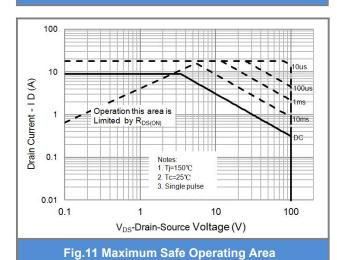


Fig.9 Threshold Voltage Variation with Temperature



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Fig.8 Breakdown Voltage Variation vs. Temperature

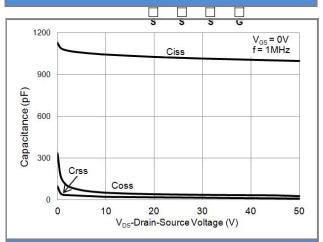


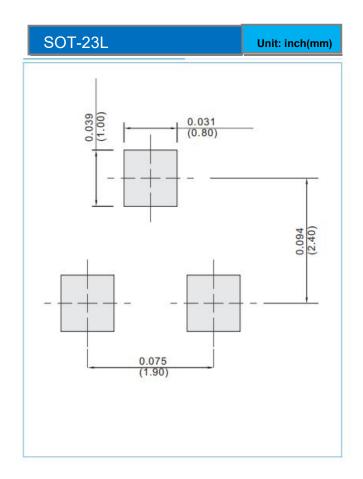
Fig.10 Capacitance vs. Drain-Source Voltage



#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type		
CSM1020N5S23L	SOT-23L	3,000pcs / 13" reel		

### **MOUNTING PAD LAYOUT**





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